



## Tutorial Session

- **Date / Time:** May 24 (Tue.), 2022 / 09:00–12:00
- **Place:** Convention Hall A
- **Session Chair:** Okhyun Nam (TU-KOREA, Korea), Yun-Ji Shin (KICET, Korea)

Time	Title	Presenter
09:00–09:40	Fabrication of AlN Templates with Dislocation Densities of $10^7\text{cm}^{-2}$ by High-Temperature Annealing	<b>Prof. Hideto Miyake</b> <i>(Mie University, Japan)</i>
09:40–10:20	Gallium Oxide Materials and Devices for Next Generation UWBG Semiconductor Technologies	<b>Prof. Sriram Krishnamoorthy</b> <i>(University of California, Santa Barbara, USA)</i>
10:20–10:35	Break	
10:35–11:15	Diamond Semiconductors: Current Status of Single Crystal Growth and Device Technologies	<b>Prof. Okhyun Nam</b> <i>(TU-KOREA, Korea)</i>
11:15–11:55	Boron Nitride: Growth and Optical Properties of its Polytypes, or What Makes $\text{Sp}^2$ Hybridization So Special	<b>Prof. Guillaume Cassabois</b> <i>(University of Montpellier, France)</i>